

DATA SHEET

SILICON TRANSISTOR ARRAY μ PA1428A

NPN SILICON POWER TRANSISTOR ARRAY HIGH SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

DESCRIPTION

The μ PA1428A is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber 4 circuits designed for driving solenoid, relay, lamp and so on.

FEATURES

- Surge Absorber built in.
- Easy mount by 0.1 inch of terminal interval.
- High hre for Darlington Transistor.

ORDERING INFORMATION

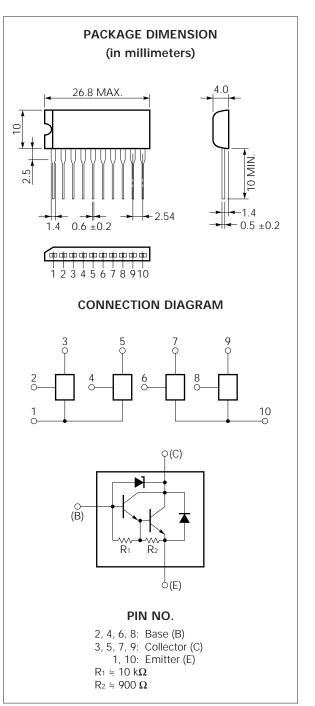
Part Number	Package	Quality Grade	
μΡΑ1428AH	10 Pin SIP	Standard	

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Исво	60 ±10	V				
Collector to Emitter Voltage	Vceo	60 ±10	V				
Emitter to Base Voltage	Vebo	8	V				
Surge Sustaining Energy	Eceo(sus)	30	mJ/unit				
Collector Current (DC)	IC(DC)	±2	A/unit				
Collector Current (pulse)	C(pulse)*	±3	A/unit				
Base Current (DC)	B(DC)	0.2	A/unit				
Total Power Dissipation	PT1**	3.5	W				
Total Power Dissipation	PT2***	28	W				
Junction Temperature	Tj	150	°C				
Storage Temperature	Tstg -5	5 to +15	50 °C				
* PW \leq 350 μ s, Duty Cycle \leq 2 %							
** 4 Circuits, Ta = 25 °C							

*** 4 Cuircuits, Tc = 25 °C



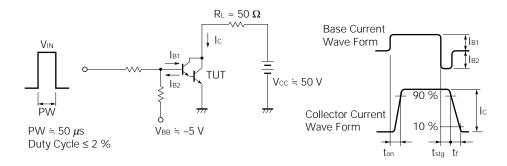
The information in this document is subject to change without notice.

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

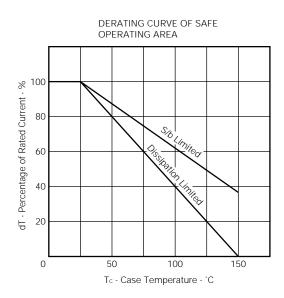
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Leakage Current	Ісво			1	μA	$V_{CB} = 40 V, I_{E} = 0$	
Emitter Leakage Current	Ево			5	mA	$V_{EB} = 5 V, Ic = 0$	
Collector to Emitter Sustaining Voltage	VCEO(sus)	50	60	70	V	Ic = 1 A, L = 1 mH	
DC Current Gain	hfei *	2000		20000	_	Vce = 2 V, Ic = 1 A	
DC Current Gain	hfe2 *	500			—	$V_{CE} = 2 V$, $I_C = 2 A$	
Collector Saturation Voltage	VCE(sat) *		1.0	1.5	V	Ic = 1 A, IB = 1 mA	
Base Saturation Voltage	VBE(sat) *		1.7	2	V	Ic = 1 A, I _B = 1 mA	
Turn On Time	ton		0.4		μs	$ \begin{array}{l} I_{C} = 1 \ A \\ I_{B1} = -I_{B2} = 2 \ mA \\ V_{CC} \doteq 50 \ V, \ R_{L} = 50 \ \Omega \\ See \ test \ circuit \end{array} $	
Storage Time	tstg		1.5		μs		
Fall Time	tr		0.4		μs		

* PW \leq 350 μ s, Duty Cycle \leq 2 %/pulsed

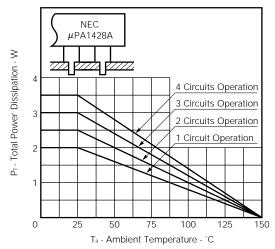
SWITCHING TIME TEST CIRCUIT



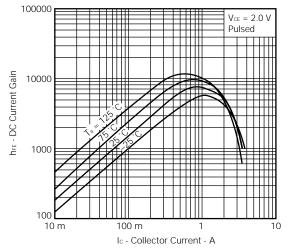
TYPICAL CHARACTERISTICS (Ta = 25 °C)

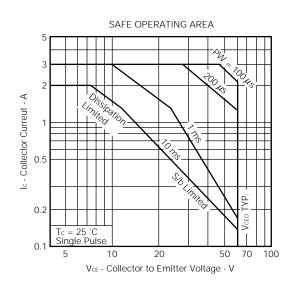


TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

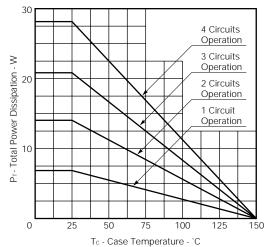




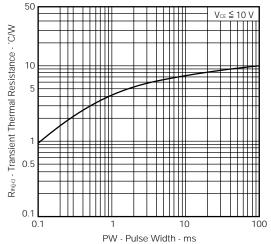


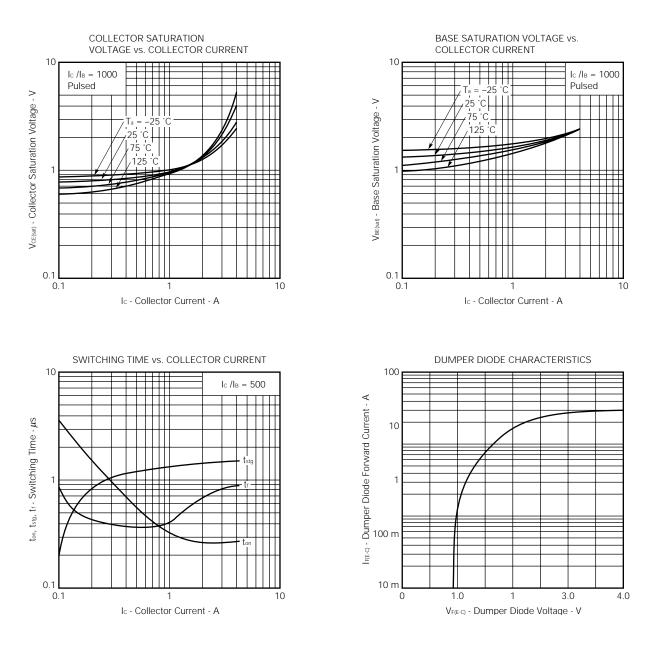


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



TRANSIENT THERMAL RESISTANCE





REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

[MEMO]

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

The devices listed in this document are not suitable for use in aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or they intend to use "Standard" quality grade NEC devices for applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

M4 92.6